

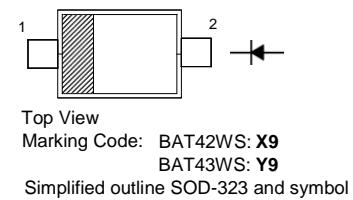
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

- Low Forward Voltage
- Fast Switching
- Ultra-Small Surface Mount Package

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

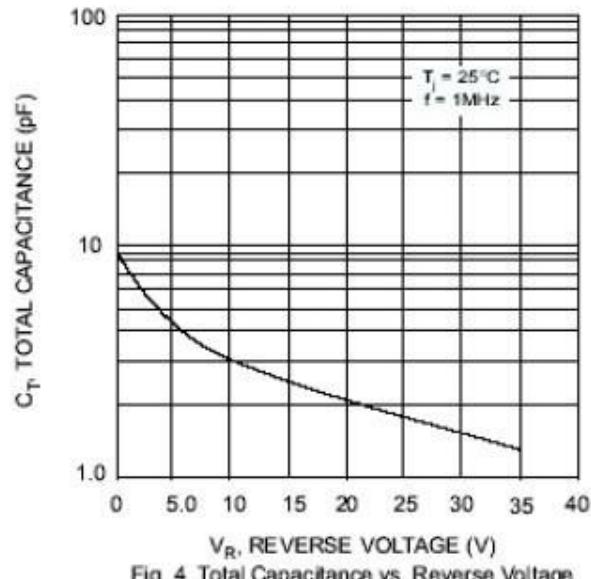
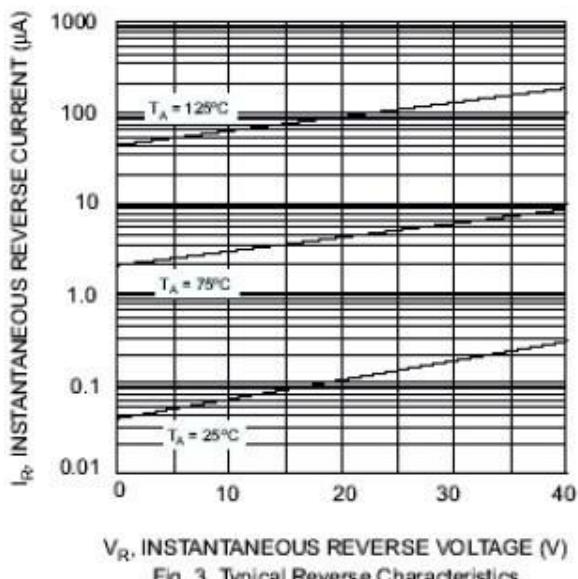
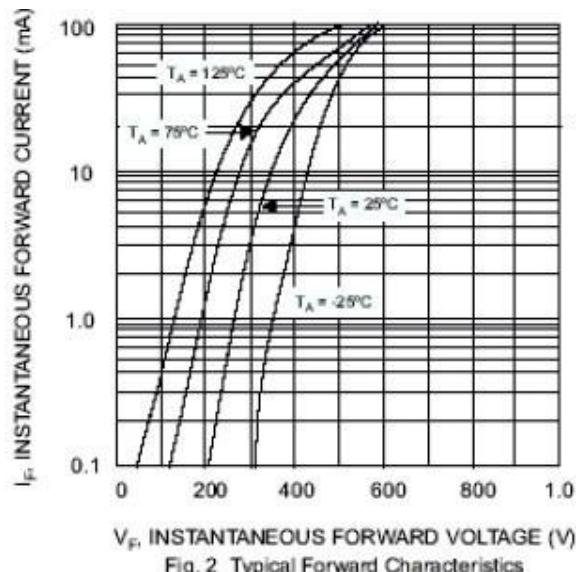
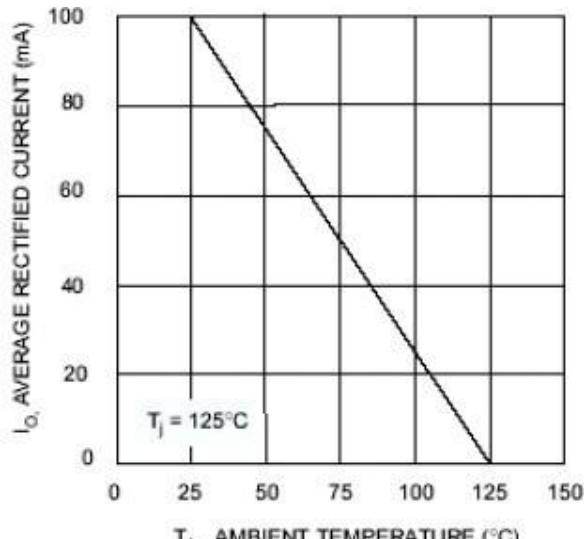


Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	30	V
Reverse Voltage	V_R	30	V
Average Rectified Output Current	I_o	100	mA
Forward Continuous Current	I_{FM}	200	mA
Repetitive Peak Forward Current at $t < 1\text{ s}$	I_{FRM}	500	mA
Non-repetitive Peak Forward Surge Current at $t < 10\text{ ms}$	I_{FSM}	2	A
Power Dissipation	P_{tot}	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	°C/W
Junction Temperature	T_j	-55 to +125	°C
Storage Temperature Range	T_{Stg}	-55 to +125	°C

Characteristics at $T_a = 25^\circ\text{C}$

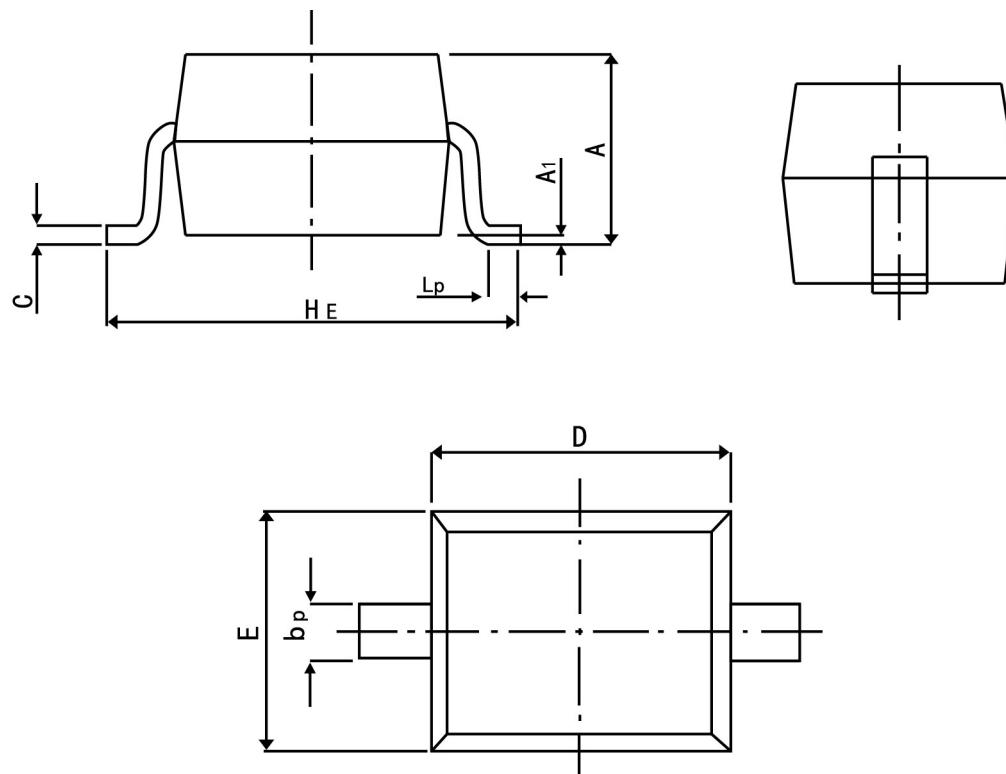
Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$	$V_{(BR)R}$	30	-	V
Reverse Current at $V_R = 25\text{ V}$	I_R	-	1	uA
Forward Voltage at $I_F = 200\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 50\text{ mA}$ at $I_F = 2\text{ mA}$ at $I_F = 15\text{ mA}$	V_F	-	1	V
			0.4	
			0.65	
		0.26	0.33	
			0.45	
Total Capacitance at $V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_T	-	10	pF
Reverse Recovery Time at $I_F = I_R = 10\text{ mA}$, $I_{RR} = 0.1 \times I_R$, $R_L = 100\text{ }\Omega$	t_{rr}	-	5	ns



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



Symbol	Dimension in Millimeters	
	Min	Max
A	0.90	1.20
bp	0.25	0.40
C	0.10	0.15
D	1.60	1.80
E	1.15	1.35
HE	2.30	2.80
A1	0.01	0.10
Lp	0.20	0.50